

APPROVAL SHEET

Customer:	
Description:	MEMS Microphone
Model:	CMM3125AT-100H58S423
·	
Customer P/N:	

Issued by	Checked by	Appoved by	Customer

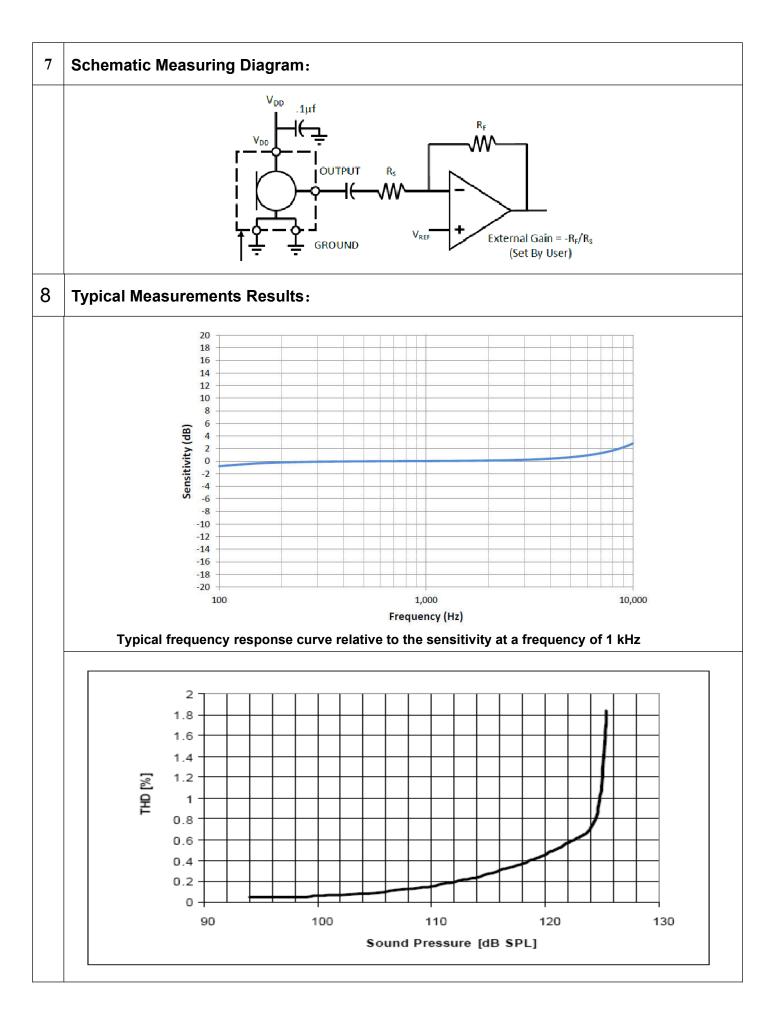
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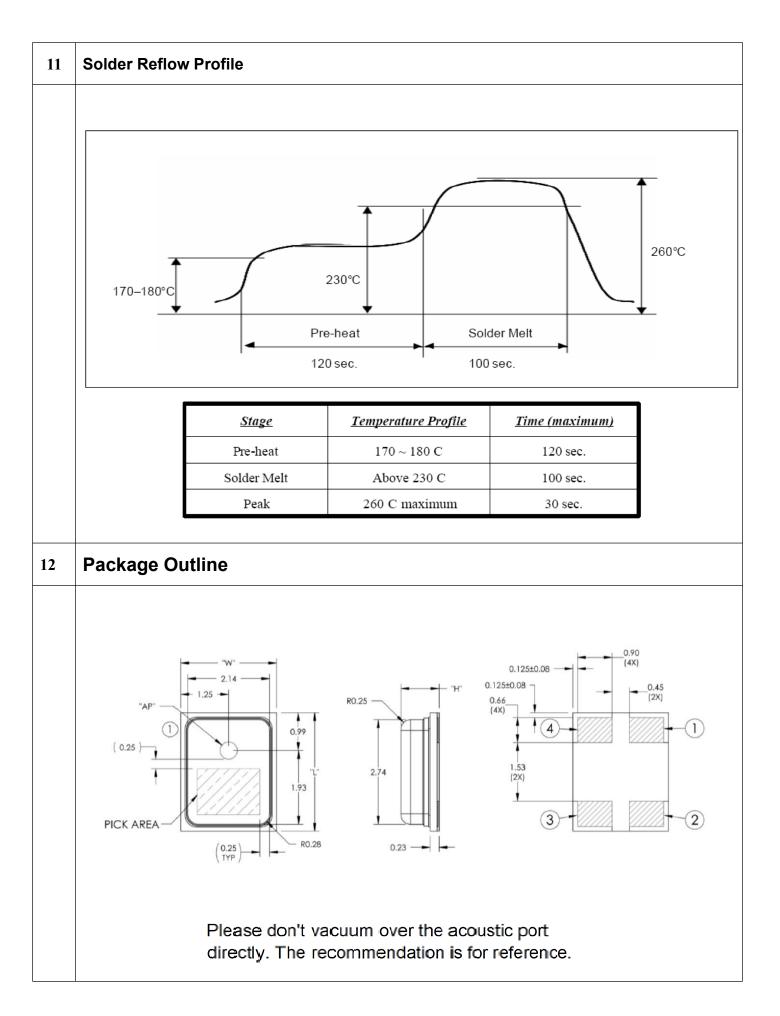
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	Feature	IS: ⊤
	3.1	SMD MEMS microphone for automated surface mount assembly
	3.2	Reflow soldering up to 260°C (Lead free)
	3.3	High long-term temperature stability
	3.4	Stable sensitivity over power supply range of 1.6~3.6V
	3.5	Low current consumption of 95uA
	3.6	Excellent power supply rejection of -66dB
	3.7	High integrated immunity to EMI
	3.8	RoHS-compliant, halogen-free package with small footprint and low height of 1.25mm
3	Applicat	ions. The CMM3125AT-100H58S423 is designed for:
	4.1	Mobile Phones (Handsets, Headsets)
	4.2	Consumer (Game Consoles, PDA's)
	4.3	Computer (Personal Computers, Notebooks)
	4.4	Cameras (Digital Still Cameras, Video Cameras)
	4.5	Navigation Device(Portable GPS)
	4.6	Blue-tooth (Headsets)
	Product	Description
-		re Silicon MEMS (Micro Electro Mechanical System) Omni-directional Microphone with
		aded analog interface designed for automated reflow soldering assembly as SMD (Surface
	-	Device) component. It is an alternative to conventional ECMs (Electret Condenser
	Microph	
	-	s robust design with a metallic lid and monolithic integrated EMI-blocking capacitors and
		on of Silicon MEMS technology, the CMM3125AT-100H58S423 shows high immunity to
		ectromagnetic Interference) and heat.
		bed Chip-On-Board package solution contains the micromechanical sensor chip and an
		r chip. The RoHS-compliant halogen-free device has a size of 3.1 x 2.5 x 1.0 mm3.
	Circuit I	
5		///////////////////////////////////////

Pin No.	Symbol				Function	
1	OUT				Output	
2	GND				Ground	
3	GND				Ground	
4	V _{DD}				Power	
Maximum Ratings						
Storage Temperature	Тѕтс				-40°C ~ 14	0°C
Operating Temperature Range	TA				-40°C ~ 12	5°C
Operating Voltage Range	Vdd				1.6 V~ 3.6	V
Typical robustness to electros	static disch	arge				
ESD capability all pins (HBM, JE	ESD22-A114	4)		V_{ESD_HBM}		± 2.5 kV
ESD capability all pins (MM, JES	SD22-A115))		V_{ESD_MM}		± 500 V
Acoustical and Electrical Charact	eristics		·		·	
Unless otherwise noted, typical	test conditic	ons are T	′ _A = 23	°C, V_{DD} = 2	2.0 V and R.I	H. = 50 %
measured in a pressure chambe	er test setup	. All volta	ages re	fer to GNE) node	
Parameter	Symbol	Values	5		Unit	Note / Test Condition
		Min.	Тур.	Max.		
Sensitivity 1 kHz	S1kHz	-45	-42	-39	dB(V/Pa)	1 kHz, 94 dB SPL
	⊗S4kHz	-1		+4	dB	Relative to sensitivity 1 kHz
Relative Sensitivity 4 kHz	O D HILL	-	-			
Relative Sensitivity 4 kHz Relative Sensitivity 240 Hz	S240Hz	-1		+1	dB	Relative to sensitivity 1 kHz
•		-1	10	+1	dB %	Relative to sensitivity 1 kHz 130 dB SPL @1 kHz
Relative Sensitivity 240 Hz	⊗S240Hz	-1	10 58			
Relative Sensitivity 240 Hz Acoustic Overload Point	⊗S240Hz	-1			%	130 dB SPL @1 kHz 94dB SPL @ 1kHz
Relative Sensitivity 240 Hz Acoustic Overload Point Signal-to-Noise Ratio	⊗S240Hz AOP	-1	58		% dB(A)	130 dB SPL @1 kHz 94dB SPL @ 1kHz A-weighted
Relative Sensitivity 240 Hz Acoustic Overload Point Signal-to-Noise Ratio Total Harmonic Distortion	⊗S240Hz AOP THD	-1	58	120	% dB(A) %	130 dB SPL @1 kHz 94dB SPL @ 1kHz A-weighted 94 dB SPL, 1 kHz <i>V</i> _{DD} = 2.0 V
Relative Sensitivity 240 Hz Acoustic Overload Point Signal-to-Noise Ratio Total Harmonic Distortion Current Consumption	⊗S240Hz AOP THD Idd	-1	58 1 95	120	% dB(A) % u A	130 dB SPL @1 kHz 94dB SPL @ 1kHz A-weighted 94 dB SPL, 1 kHz

2) Noise measurement with A-weighting filter (IEC 651)



	Note: After test condition than 3dB from its initial va	s are performed, the sensitivity of the microphone shall not deviate more
	Test	Description
	Thermal Shock	Microphone unit must operate when exposed to air-to-air thermal shock 100 cycles, from -40°C to +125°C. (IEC 68-2-4),
	High Temperature Storage	Microphone unit must maintain sensitivity after storage at +105°C for 1,000 hours. (IEC 68-2-2 Test Ba)
	Low Temperature Storage	Microphone unit must maintain sensitivity after storage at -40°C for 1,000 hours. (IEC 68-2-1 Test Aa)
	High Temperature Operating Test	Microphone unit must operate within sensitivity specifications for 1,000 hours at 105°C. (IEC 68-2-2 Test Ba)
	Low Temperature Operating Test	Microphone unit must operate within sensitivity specifications for 1,000 hours at -40°C. (IEC 68-2-1 Test Aa)
	Humidity Test	Tested under Bias at 85°C/85% R.H. for 1,000 hours. (JESD22-A101A-B)
	Vibration Test	Microphone unit must operate under test condition: 4 cycles, from 20 to 2,000 Hz in each direction (x,y,z), 48 minutes, using peak acceleration of 20 G (+20%, -0%). (MIL 883E, method 2007.2, A)
	Electrostatic Discharge	Tested to 2kV direct contact discharge or 8kV air discharge as specified by IEC 1000- 4-2, level 3 and level 4.
	Reflow	Microphone is tested to 5 passes through reflow oven, with microphone mounted upside-down under conditions of 260°C for 30 seconds maximum.
	Mechanical Shock	Microphone must operate after exposure to shock test of 10,000 G per IEC 68-2-27, Ea.
0	Notes:	
	1. Do not pull a vacuum	over the port hole of the microphone. Pulling a
	vacuum over the port ho	ble can damage the device.
	2. Do not board wash at	fter the reflow process. Board washing and
	cleaning agents can dar	mage the device. Do not expose to ultrasonic
	processing or cleaning.	
	3. Number of Reflow = r	ecommend no more than 3 cycles.
	4. elf life: Twelve (12) m	onths when devices are to be stored in factory supplied, unopened
		bag under maximum environmental conditions of 30°C, 70% R.H.
		ould not be exposed to high humidity, high temperature environment.
	MSL (moisture sensitivit	
		of 90 days out of ESD moisture sensitive bag, assuming maximum



	ltem		Dimension	Tolerance
	Length (L)		3.10	±0.10
	Width (W)		2.50	±0.10
	Height (H)		1.00	±0.10
	Acoustic Port	(AP)	Ø0.45	±0.05
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Pin #	Pin Name	Тур	e	Description
1	OUTPUT	Sign	al (Output Signal
2	GROUND	Pow	er	Ground
3	GROUND	Pow	er	Ground
8		1 0.000		Ground
4 Notes	V _{DD} Pick Area only exten	Powe	193 S	Power Supply ole unless otherwis wise specified.
Notes	V _{DD} Pick Area only exten	Powe nds to 0.25 s are in mil s ±0.15mn	er I mm of any edge or h llimeters unless other	Power Supply ole unless otherwise wise specified.

